

Enhanced 900 A 1700 V ED Module with Micropattern Trench IGBT for High Performance and Reliability

Nick Schneider, SwissSEM Technologies AG

Introduction and motivation



- ED type modules are a staple of the power electronics industry
- Widely used in industrial drives, renewable energy and automotive applications
- Highly scaled and standard footprint -> large focus on economical value

Main design focus:

- → Provide best possible \$/A performance
- → Rugged, low loss chipset
- → Suitable for a wide variety of applications



SwissSEM

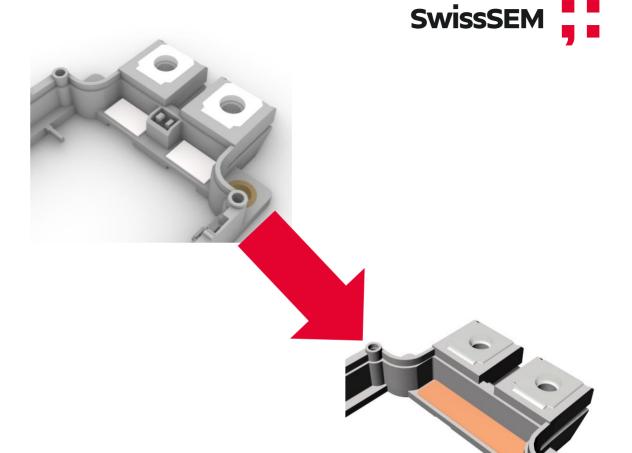
Summary

Main focus: improve module while reducing cost

- → Improve current carrying capability
- → Enhance power & thermal cycling reliability
- → Reduce coupling on the IGBT for improved switching
- → Enable more chip area for higher power density

Improved current carrying capability

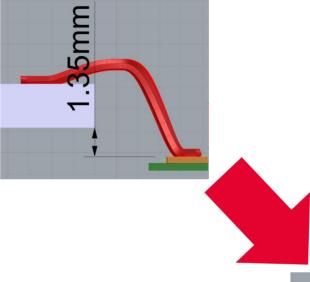
- Optimized power terminals for more bondable area
- Bare copper metallization for more stable bonding

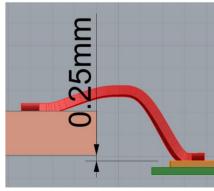


SwissSEM

Improved current carrying capability

- Optimized power terminals for more bondable area
- Bare copper metallization for more stable bonding
- 20mil copper wires & shorter loops on the terminals



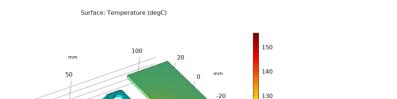


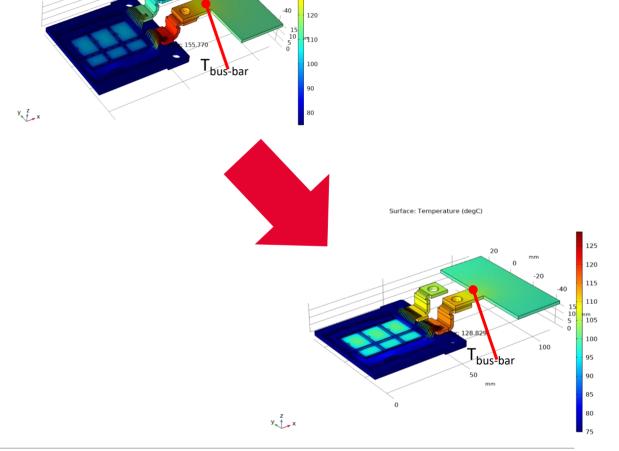
Improved current carrying capability

- · Optimized power terminals for more bondable area
- Bare copper metallization for more stable bonding
- 20mil copper wires & shorter loops on the terminals

→ The improvements lead to an average reduction in terminal temperature of more than 30 %







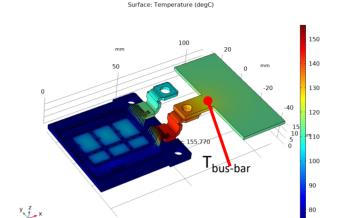
Improved current carrying capability

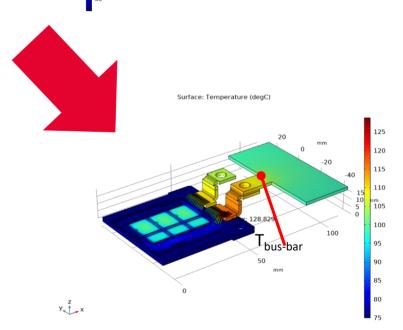
- · Optimized power terminals for more bondable area
- Bare copper metallization for more stable bonding
- 20mil copper wires & shorter loops on the terminals

→ The improvements lead to an average reduction in terminal temperature of more than 30 %

Terminal type	750 A Design (K)	900 A Design (K)	Delta (K)	Delta (%)
DC+	72.2	50.9	21.3	29.5
DC-	82.4	52.9	29.5	35.8
AC	61	44	17	27.9



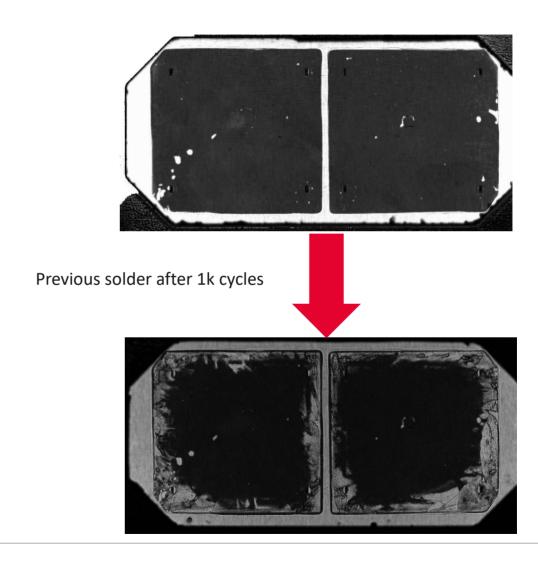




SwissSEM ...

Enhanced thermal cycling reliability

- The soldering is improved for both the die attach and the substrate to baseplate
- A novel solder material is used to greatly increase the reliability of the solder joints

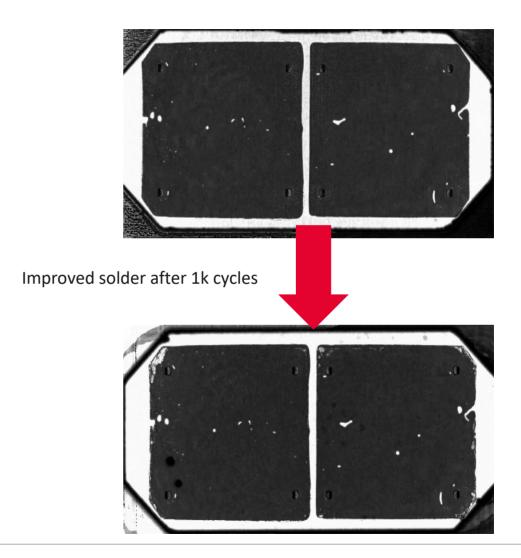


SwissSEM ...

Enhanced thermal cycling reliability

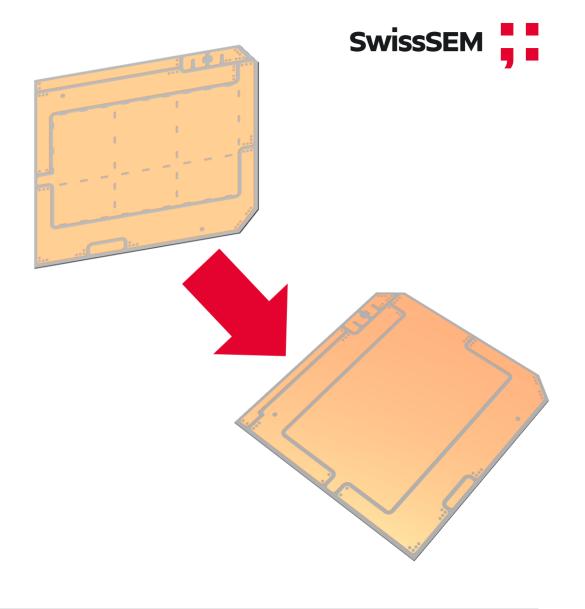
- The soldering is improved for both the die attach and the substrate to baseplate
- A novel solder material is used to greatly increase the reliability of the solder joints

$$T_{min}$$
 = -40 °C, T_{max} = 125 °C, t_{change} = 3 s, t_{hold} = 30 min



Improved DBC substrate layout

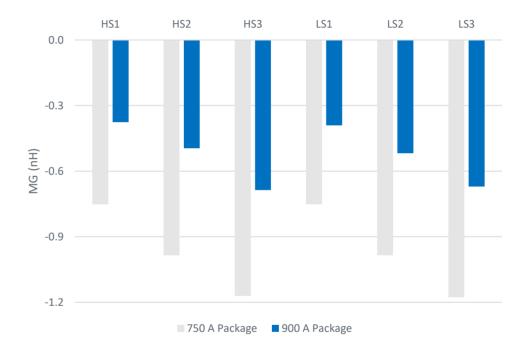
• More chip area, more flexible chip placement



SwissSEM

Improved DBC substrate layout

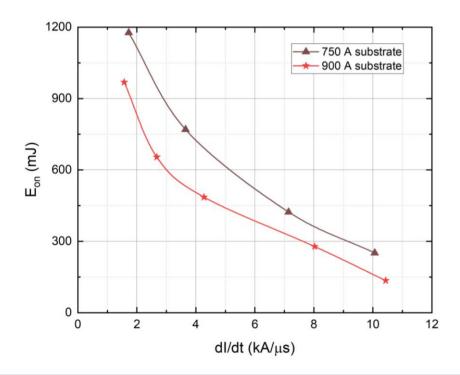
- More chip area, more flexible chip placement
- Reduced GE coupling for improved switching behavior
- → GE coupling is reduced by 30 50 %

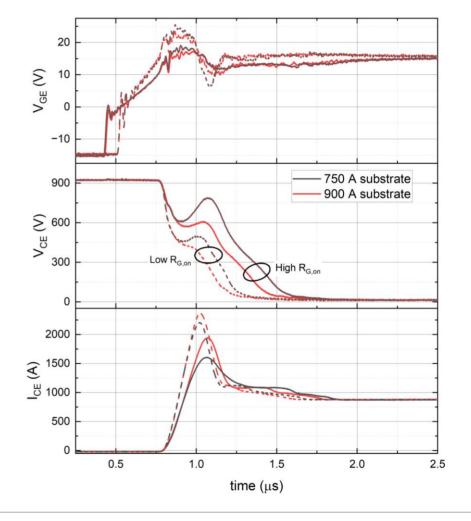


SwissSEM ...

Improved DBC substrate layout

- More chip area, more flexible chip placement
- Reduced GE coupling for improved switching behavior
- Faster switching, reduced Eon





IGBT cell design

LC³ IGBT

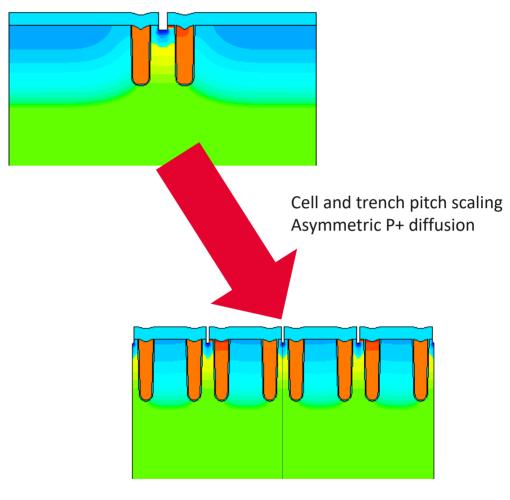
IGBT cell improvement drivers:

- → Higher cell density by feature size shrinking
- → Optimized arrangement of gate and emitter trenches
- → Carrier confinement

Conduction and switching losses can be improved, but we need to consider:

- → Turn-off controllability (Peak voltage at turn-off)
- → Reverse bias safe operating area (RBSOA)
- → Short-circuit safe operating area (SCSOA)
- → Micropattern trench IGBT with LC³-concept allows further improvement on the technology curve while keeping controllability





Diode design

OLLC Diode

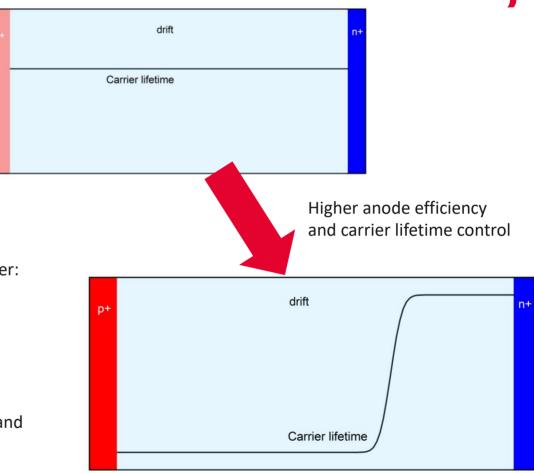
Diode improvement drivers:

- → Anode injection tuning
- → Carrier lifetime control
- → Drift region thickness

Conduction and switching losses can be improved, but we need to consider:

- → Soft recovery behavior
- → Diode safe operating area (DSOA)
- → Temperature coefficient
- → Diode with novel QLLC technology allows for increased emitter dose and thinner drift region while keeping the soft recovery behavior



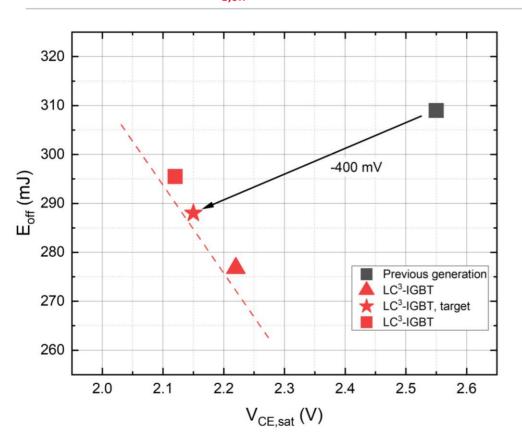


Technology curve

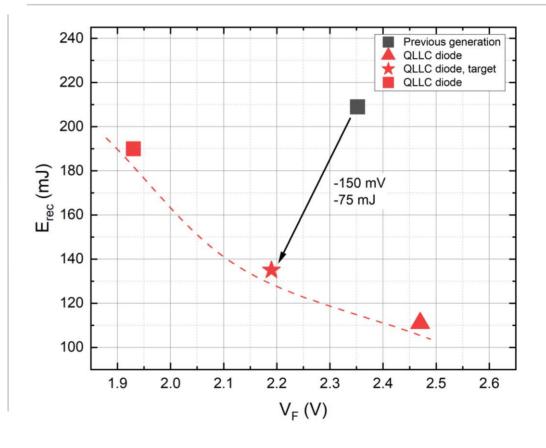


900 A, 900 V, L_{σ} = 35 nH, 175 °C

Technology curve IGBT ($R_{G,off} = 0.5 \Omega$)



Technology curve Diode ($dI/dt = 9 kA/\mu s$)

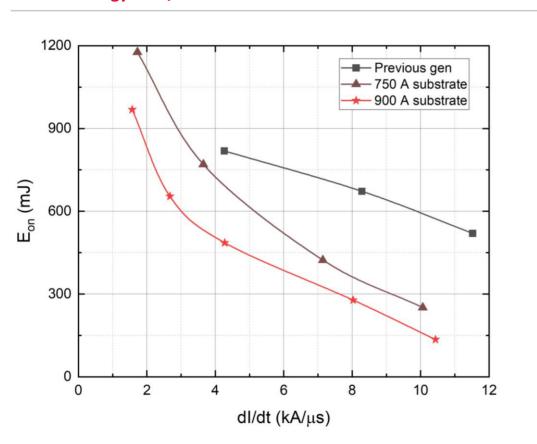


IGBT turn-on

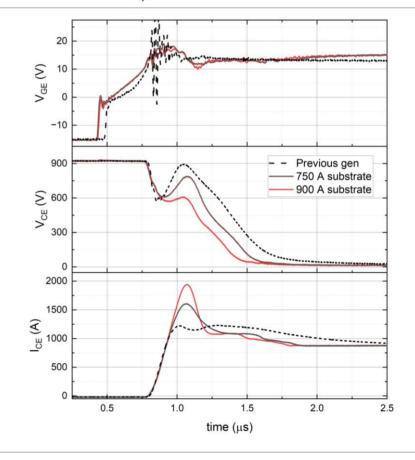


900 A, 900 V, L_{σ} = 35 nH, 175 °C

Turn-on energy vs dI/dt



Turn-on waveform ($R_{G,on} = 0.5 \Omega$, 1.5 Ω for previous gen)

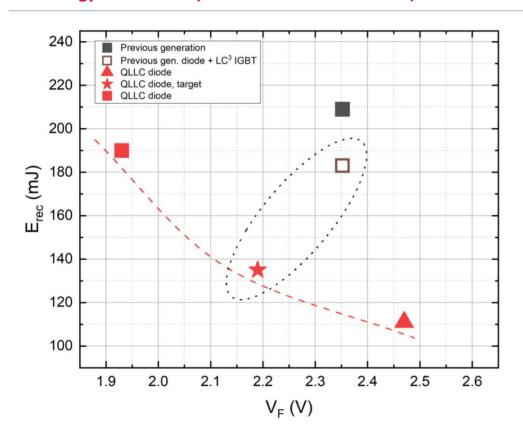


Diode recovery

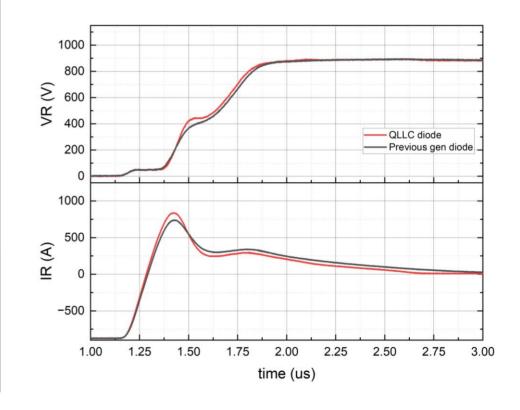


900 A, 900 V, $R_{G,on}$ = 0.5 Ω , L_{σ} = 35 nH, 175 °C

Technology curve diode (both diodes with new IGBT)



Recovery waveform ($R_{G,on} = 0.5 \Omega$)



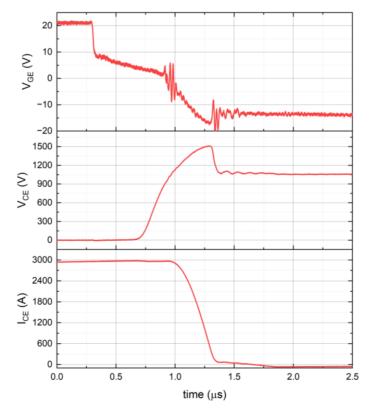
Safe operating area

SwissSEM |

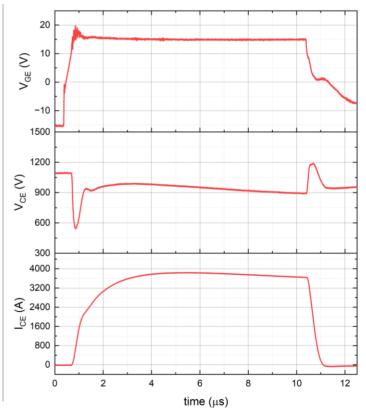
RBSOA / SCSOA L_{σ} = 35 nH, 175 °C

- The novel LC³ IGBT is extremely robust in both RBSOA and SCSOA
- Large margin in SOA improves yield and reduces risk of failures in the field

RBSOA, 1100 V, 3000 A



SCSOA, 1100 V, 10 μs

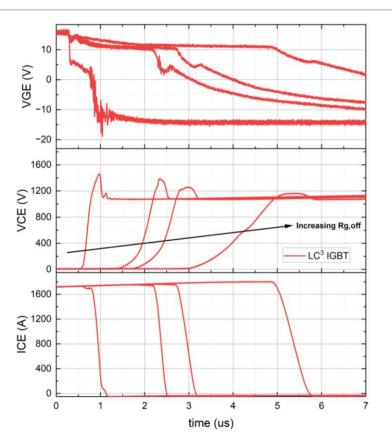


Turn-off controllability waveforms

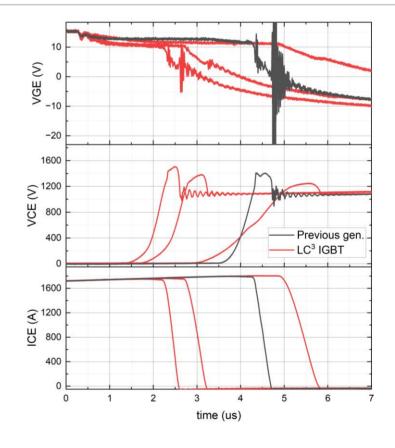


 I_{CE} = 1800 A, V_{CC} = 1100 V, $R_{G,off}$ = 0.5 ... 40 Ω , 25 °C

$$L_{\sigma} = 35 \text{ nH}$$



 $L_{\sigma} = 95 \text{ nH}$

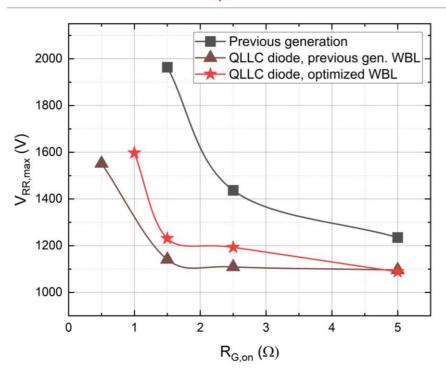


Diode softness

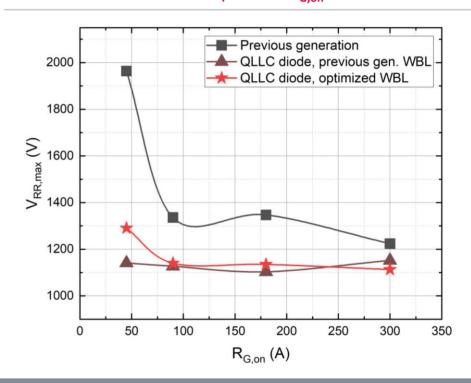


1100 V, $I_F = 45A$, $L_{\sigma} = 95$ nH, 25 °C

Peak recovery voltage vs R_{G.on}



Diode softness waveforms, I_F = 45 A, $R_{G,on}$ = 1.5 Ω



→ Improved diode shows significantly improved softness and lower losses at the same time

Summary and conclusion



Summary:

- The enhanced 900 A ED packaging from SwissSEM Technologies has been introduced
- The new module features improved power terminal design, optimized bond-wire layout and DBC design, as well as a more reliable solder material
- A new 1.7 kV 900 A chipset has been developed and the results shown

Conclusion:

- The new SwissSEM 900 A ED module features higher current carrying capability, better thermal cycling performance and enables faster switching
- The novel chipset features class leading losses and SOA ruggedness
- Inquire at our booth (N5 C01) for sample availability
- Check our website for detailed product information: https://www.swiss-sem.com/product-catalogue



mesago

pcim

6 – 8.5.2025 NUREMBERG, GERMANY

Thank you for the attention!

I'm pleased to answer your questions.

nick.schneider@swiss-sem.com

Messe Frankfurt Group